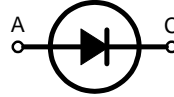


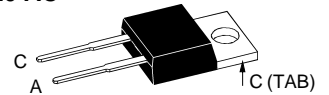
# Rectifier Diode

$$V_{RRM} = 800-1600 \text{ V}$$

$$I_{F(AV)M} = 30 \text{ A}$$

$V_{RSM}$ V	$V_{RRM}$ V	TO-220	TO-263
900	800	DSI 30-08A	DSI 30-08AS
1300	1200	DSI 30-12A	DSI 30-12AS
1500	1400	DSI 30-14A	DSI 30-14AS
1700	1600	DSI 30-16A	DSI 30-16AS


**TO-263 AA**

**TO-220 AC**


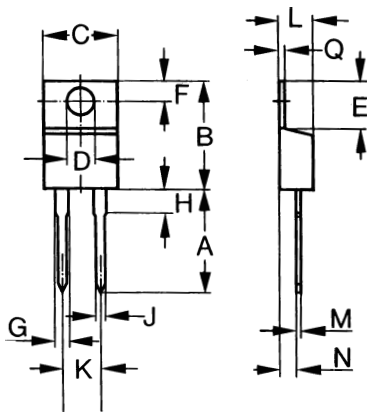
A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum Ratings	
$I_{F(AV)M}$	$T_C = 95^\circ\text{C}; 180^\circ \text{ sine}$	30	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}; t = 10 \text{ ms (50 Hz), sine}$	300	A
	$V_R = 0 \text{ V}; t = 8.3 \text{ ms (60 Hz), sine}$	330	A
	$T_{VJ} = 150^\circ\text{C}; t = 10 \text{ ms (50 Hz), sine}$	270	A
	$V_R = 0 \text{ V}; t = 8.3 \text{ ms (60 Hz), sine}$	300	A
$I^2t$	$T_{VJ} = 45^\circ\text{C}; t = 10 \text{ ms (50 Hz), sine}$	450	A <sup>2</sup> s
	$V_R = 0 \text{ V}; t = 8.3 \text{ ms (60 Hz), sine}$	460	A <sup>2</sup> s
	$T_{VJ} = 150^\circ\text{C}; t = 10 \text{ ms (50 Hz), sine}$	365	A <sup>2</sup> s
	$V_R = 0 \text{ V}; t = 8.3 \text{ ms (60 Hz), sine}$	380	A <sup>2</sup> s
$T_{VJ}$		-40...+150	°C
$T_{VJM}$		150	°C
$T_{stg}$		-40...+150	°C
$M_d$	Mounting torque	0.4...0.6	Nm
<b>Weight</b>		2	g

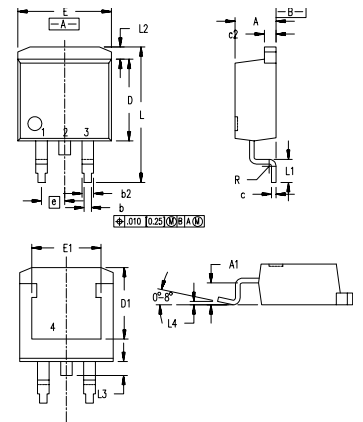
**Features**

- International standard packages
- JEDEC TO-263 AA surface mountable
- Planar passivated chips
- Epoxy meets UL 94V-0 flammability classification

Symbol	Conditions	Characteristic Values	
$I_R$	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	≤ 1	mA
$V_F$	$I_F = 45 \text{ A}; T_{VJ} = 25^\circ\text{C}$	≤ 1.45	V
$V_{T0}$	For power-loss calculations only	0.85	V
$r_T$	$T_{VJ} = T_{VJM}$	13	mΩ
$R_{thJC}$	DC current	1.0	K/W

**TO-220 Outline**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	14.73	0.500	0.580
B	14.23	16.51	0.560	0.650
C	9.66	10.66	0.380	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.420
F	2.54	3.42	0.100	0.135
G	1.15	1.77	0.045	0.070
H	-	6.35	-	0.250
J	0.64	0.89	0.025	0.035
K	4.83	5.33	0.190	0.210
L	3.56	4.82	0.140	0.190
M	0.38	0.56	0.015	0.022
N	2.04	2.49	0.080	0.115
Q	0.64	1.39	0.025	0.055

**TO-263 AA Outline**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.06	4.83	.160	.190
A1	2.03	2.79	.080	.110
b	0.51	0.99	.020	.039
b2	1.14	1.40	.045	.055
c	0.46	0.74	.018	.029
c2	1.14	1.40	.045	.055
D	8.64	9.65	.340	.380
D1	7.11	8.13	.280	.320
E	9.65	10.29	.380	.405
E1	6.86	8.13	.270	.320
e	2.54	BSC	.100	BSC
L	14.61	15.88	.575	.625
L1	2.29	2.79	.090	.110
L2	1.02	1.40	.040	.055
L3	1.27	1.78	.050	.070
L4	0	0.38	0	.015
R	0.46	0.74	.018	.029

Data according to IEC 60747 and refer to a single diode  
IXYS reserves the right to change limits, test conditions and dimensions

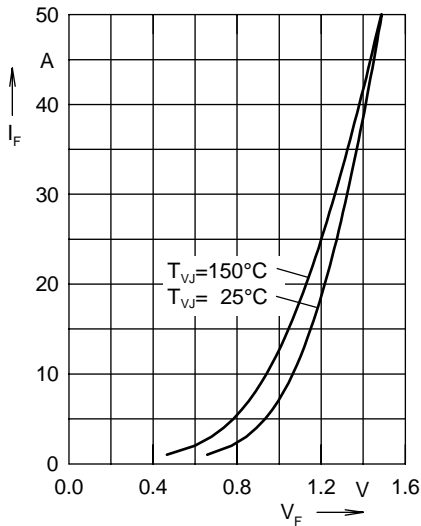


Fig. 1 Forward current versus voltage drop per diode

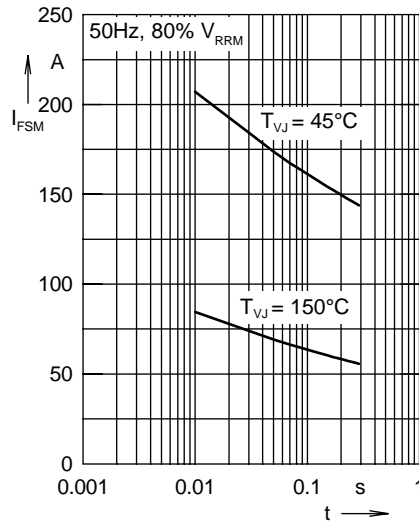


Fig. 2 Surge overload current

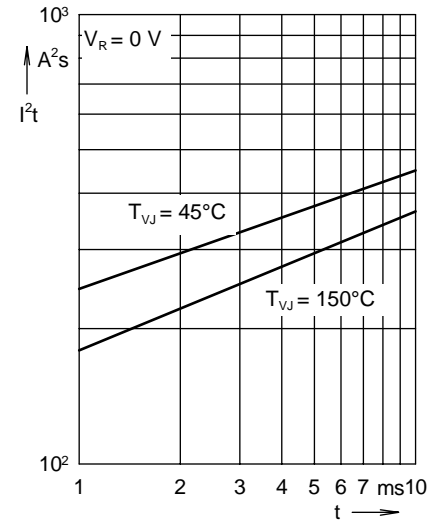


Fig. 3  $I^2t$  versus time per diode

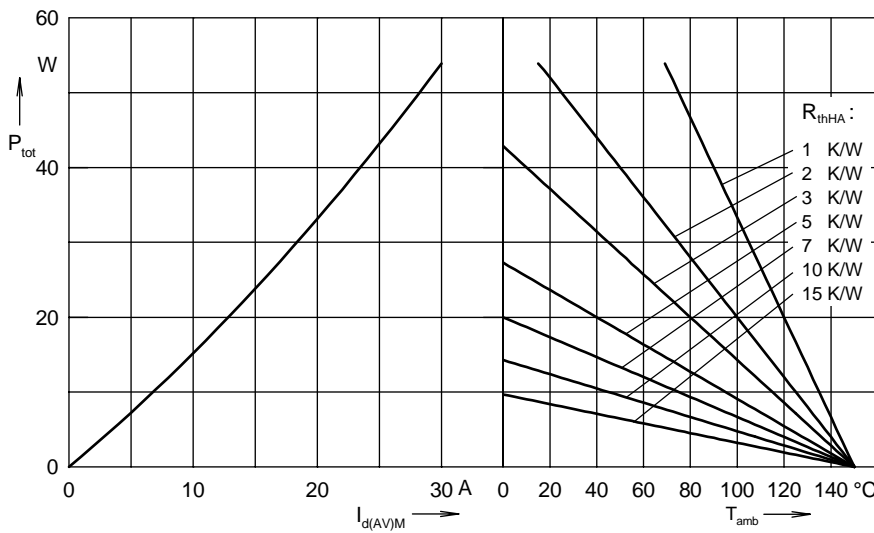


Fig. 4 Power dissipation versus direct output current and ambient temperature, sine 180°

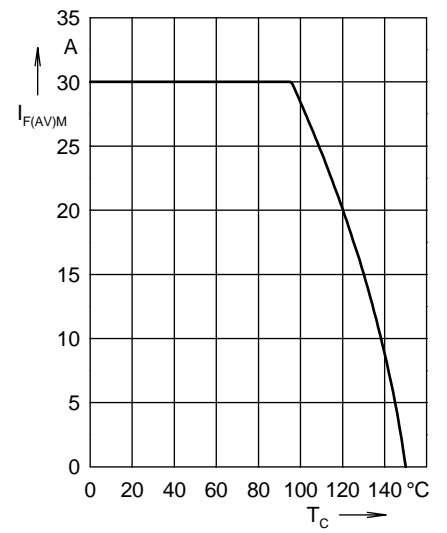


Fig. 5 Max. forward current versus case temperature

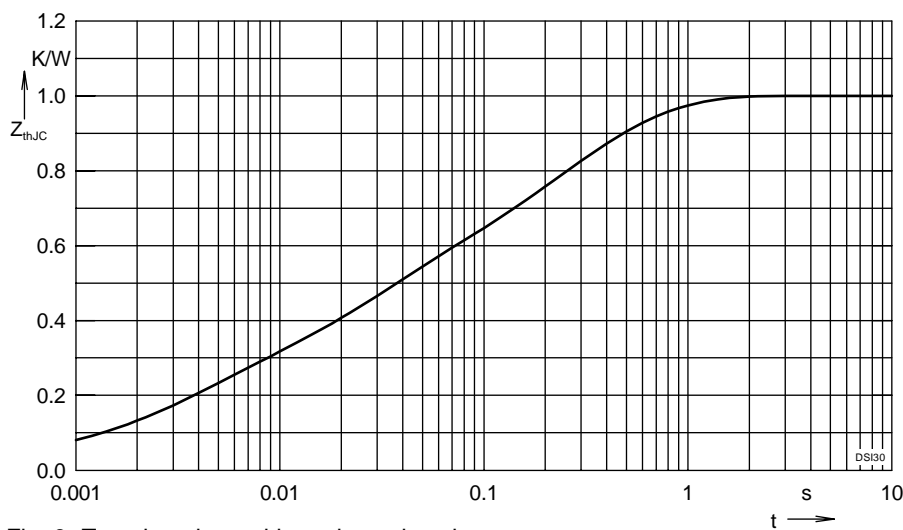


Fig. 6 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.01362	0.0001
2	0.1962	0.00316
3	0.267	0.023
4	0.3052	0.4
5	0.218	0.15